PIC18F04/05/14/15Q40

PIC18F04/05/14/15Q40 Silicon Errata and Data Sheet Clarifications

The PIC18F04/05/14/15Q40 devices you have received conform functionally to the current device data sheet (DS40002236**C**), except for the anomalies described in this document.

The silicon issues discussed in the following pages are for silicon revisions with the Device and Revision IDs listed in the table below.

The errata described in this document will be addressed in future revisions of the PIC18F04/05/14/15Q40 silicon.

Note: This document summarizes all silicon errata issues from all revisions of silicon, previous as well as current.

Table 1. Silicon Device Identification

Part Number	Device ID	Revision ID				
	Device iD	D1	D3			
PIC18F04Q40	0x7640	0xA0C1	0xA0C3			
PIC18F05Q40	0x7600	0xA0C1	0xA0C3			
PIC18F14Q40	0x7620	0xA0C1	0xA0C3			
PIC18F15Q40	0x75E0	0xA0C1	0xA0C3			



Important: Refer to the **Device/Revision ID** section in the current "**PIC18FXXQ40 Family Programming Specification**" (DS40002185) for more detailed information on Device Identification and Revision IDs for your specific device.

Table 2. Silicon Issue Summary

Madala	F4	Maria Na		Affected Revisions			
Module	Feature	Item No.	Issue Summary	D1	D3		
Analog-to-Digital Converter with Computation	ADCC	1.1.1.	Double Sample Conversions	Х	X		
Electrical Specifications	ADC Offset Error	1.2.1.	ADC Offset Error specification lowered in ECH, ECM and ECL modes	X			
I ² C	I ² C	1.3.1.	I ² C Start and/or Stop Flags May be Set When I ² C is Enabled	X			
Universal Asynchronous	UART	1.4.1.	UART TXDE signal may go low before the STOP bit has been entirely transmitted.	×	×		
Receiver Transmitter		1.4.2.	Asynchronous 9- bit UART Address Mode Address Mismatch	×	×		
Signal Measurement TImer	SMT	1.5.1.	Reset Bit	X	X		
PIC18 CPU	FSR Shadow Registers	1.6.1.	FSR Shadow Registers are not Writable	X	X		

Note: Only those issues indicated in the last column apply to the current silicon revision.

1. Silicon Errata Issues

CAUTION

Notice: This document summarizes all silicon errata issues from all revisions of silicon, previous as well as current. Only the issues indicated by the bold font in the following tables apply to the current silicon revision.

1.1 Module: Analog-to-Digital Converter with Computation (ADCC)

1.1.1 Double Sample Conversions

When enabling a Double Sample Conversion (DSEN = 1), with no Precharge time (ADPRE = 0) and no Acquisition time (ADACQ = 0), the maximum number of cycles of acquisition time is inserted prior to the second conversion. The first conversion will be performed as expected with no Precharge time and no Acquisition time. It is only between the first and second conversions where a maximum number of cycles of Acquisition time is performed unexpectedly.

Work around

- Method 1: Disable Double Sample Conversion (DSEN = 0) and perform two single conversions back to back.
- Method 2: If adding acquisition time is acceptable, then select no Precharge time, along with the desired Acquisition time.

Affected Silicon Revisions

D1	D3
X	X

1.2 Module: Electrical Specifications

1.2.1 ADC Offset Error Specification Lowered in ECH, ECM and ECL Modes

When operating the device using an external clock source as the system clock in ECH, ECM or ECL mode, the ADC Offset Error (AD04: E_{OFF}) is updated to 12 Least Significant bits.

Work around

To meet the specified ADC Offset Error limit of 6 Least Significant bits, do not operate the device using the system clock in ECH, ECM or ECL mode when using the ADC.

Affected Silicon Revisions

D1	D3
X	

1.3 Module: I²C

1.3.1 The I²C Start and/or Stop Flags May Be Set When I²C Is Enabled

When I²C is enabled, erroneous Start and/or Stop conditions may be detected. This can generate erroneous I²C interrupts if enabled.

Work around

Use the following procedure to correctly detect the Start and Stop conditions:

- 1. Disable the Start and Stop conditions interrupt functions.
- 2. Enable the I²C module.
- 3. Wait 250 ns + six instructions cycles (F_{OSC}/4).
- 4. Clear the Start and Stop conditions interrupt flags.
- 5. Enable the Start and Stop conditions interrupt functions if used.

```
I2CxPIEbits.SCIE = 0;
                             // Disable Start conditoin interrupt
I2CxPIEbits.PCIE = 0;
                             // Disable Stop condition interrupt
I2CxCON0bits.EN = 1;
                             // Enable I2C
                             // Wait for 250nS + 6 instruction cycles (FOSC/4)
Delay();
I2CxPIRbits.SCIF = 0;
                             // Clear the Start condition interrupt flags
I2CxPIRbits.PCIF = 0;
                             // Clear the Stop condition interrupt flags
I2CxPIEbits.SCIE = 1;
                             // Enable Start condition interrupt if used
I2CxPIEbits.PCIE = 1;
                             // Enable Stop condition interrupt if used
```

Affected Silicon Revisions

D1	D3
X	

1.4 Module: Universal Asynchronous Receiver Transmitter

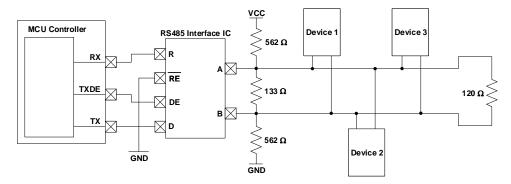
1.4.1 UART TXDE Signal May go Low Before The STOP Bit Has Been Entirely Transmitted.

The UART Transmit Drive Enable (TXDE) signal could potentially transition into a low state before the UART STOP bit has been entirely transmitted due to the effects of parasitic capacitance on the TX line. In some applications, this could result in communication being prematurely terminated due to the TXDE bit going low before the STOP bit has had enough time to settle.

Work around

In order to ensure that the STOP bit settles into its final logic state before the TXDE signal transitions low, a biasing circuit can be implemented. A biasing circuit allows the TX line to either be driven high or low, rather than being left in a floating tri-state mode where prolonged rise or fall times could lead to communication being disrupted. This bias circuit should only be implemented on one end of the serial bus, and a termination resistor should be used on the other end. The figure below show an example of a bias circuit that can be used to achieve this.

Please note that the resistor values used in this circuit are recommendations, and that the actual resistor values required may vary based on the application.



Affected Silicon Revisions

D1	D3
X	X

1.4.2 Asynchronous 9-bit UART Address Mode Address Mismatch

In Asynchronous 9-bit UART Address mode there is the possibility that a false address mismatch may occur even when the address of both devices match, or that a false address match may occur when there is an address mismatch between the devices.

Work around

None. Do not use the UART modules in Asynchronous 9-bit Address Mode

Affected Silicon Revisions

D1	D3
X	X

1.5 Module: SMT

1.5.1 Reset Bit

If the SMT clock prescaler is set to any value other than '00', setting the RST bit will cause the module to stop working. The RST bit will remain at the value '1', the counter will not increment, and no interrupts will be generated. The problem is cleared by turning the module off and on, or by a device reset.

Work around

- Method 1: Do not set the RST bit; manual reset is usually not required for typical operation because the
 measurement logic will reset the counter automatically.
- Method 2: Write zero to the counter manually. The module enable or the clock should be disabled during this.
- Method 3: Use 1:1 prescaler (PS = 00).
- Method 4: Use the CLKREF subsystem to provide a prescaled clock and set PS = 00.

Affected Silicon Revisions

D1	D3
X	X

1.6 Module: PIC18 Core

1.6.1 FSR Shadow Registers are not Writable

Writing to the FSR Shadow Registers does not result in accurate values being stored in the registers. Consequently, reading the FSR Shadow Registers after they have been written will return inaccurate data.

Work around

Writes to the FSR shadow registers can be performed safely using the following steps:

- Save regular FSR2 value into RAM
- 2. Write the regular FSR2 with the targeted value minus the computed offset (IR[6:0] + 1, see below)
- 3. Write the shadow FSRxL (data doesn't matter), this will clock the shadow FSR with the FSR computed offset value.

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- 4. Decrement FSR2 value by 1 since FSRxH increments the address by 1 (IR[6:0])
- 5. Write FSRxH
- 6. Restore the regular FSR2 from the stored RAM value.

The FSR shadow should have the value desired and the regular FSR should have the original value.

Affected Silicon Revisions

D1	D3
X	X

2. Data Sheet Clarifications

The following typographic corrections and clarifications are to be noted for the latest version of the device data sheet (DS40002236C):

Note:

Corrections are shown in bold. Where possible, the original bold text formatting has been removed for clarity.

2.1 Memory Programming Specifications

The flash memory cell endurance specification is reduced to 1k minimum. The corresponding parameter (E_P) will be updated in the next revision of datasheet (DS40002236D).

Table 2-1. Memory Programming

Daram	Cum	Davisa Characteristics	Min	Trent	Max	Units	Conditions	
Param No.	Sym.	Device Characteristics	Min.	Тур†	Max.	Units	Conditions	
Data EEPROM Memory Specifications								
MEM20	E _D	DataEE Byte Endurance	100k		_	E/W	-40°C ≤ T _A ≤ +85°C	
MEM21	T _{D_RET}	Characteristic Retention	_	40	_	Year	Provided no other specifications are violated	
MEM22	N _{D_REF}	Total Erase/Write Cycles before Refresh	1M	4M	_	E/W	-40°C ≤ T _A ≤ +85°C	
MEM23	V_{D_RW}	V _{DD} for Read or Erase/Write operation	V _{DDMIN}	_	V_{DDMAX}	V		
MEM24	T _{D_BEW}	Byte Erase and Write Cycle Time	_	_	11	ms		
Progran	n Flash M	lemory Specifications						
МЕМ30	E _P	Flash Memory Cell Endurance	1k	_	_	E/W	-40°C ≤ T _A ≤ +85°C (Note 1)	
MEM32	T _{P_RET}	Characteristic Retention	_	40	_	Year	Provided no other specifications are violated	
МЕМ33	V_{P_RD}	V _{DD} for Read operation	V _{DDMIN}	_	V_{DDMAX}	V		
MEM34	V _{P_REW}	V _{DD} for Row Erase or Write operation	V _{DDMIN}	_	V_{DDMAX}	V		
MEM35	T _{P_REW}	Self-Timed Page Write	_	_	10	ms		
MEM36	T _{SE}	Self-Timed Page Erase	_	_	11	ms		
MEM37	T _{P_WRD}	Self-Timed Word Write			75	μs		

[†] Data in "Typ" column is at 3.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note:

 Flash Memory Cell Endurance for the Flash memory is defined as: One Row Erase operation and one Self-Timed Write.

Errata

2.2 UART Baud Rate Equation

The UART Baud Rate equation in the UxBRG register contains a typo and will provide the incorrect UART Baud Rate. The correct equation is shown below. The correction to this equation is shown in bold.

UART Baud Rate = [Fosc*(1+(BRGS*3)]/[(16*(BRG+1))]

2.3 Power-Down Current (I_{PD}) Specifications

The Power-Down current (I_{PD}) electrical specifications for FVR Buffer 2 and I_{PD} Base when VREGPM = 01 have been modified. The corresponding parameters ($I_{PD_FVR_BUF2}$ and I_{PD}) will be updated in the next revision of the datasheet (DS40002236D).

Table 2-2. Power-Down Current (IPD)(1,2)

Standar	Standard Operating Conditions (unless otherwise stated)									
Param.	Sym.	Device	Min.	Typ.†	Max.	Max.	Units		Conditio	ons
No.		Characteristics			+85°C	+125°C	25°C	V _{DD}	VREGPM	Note
D200	I _{PD}	I _{PD} Base	_	1.1	3.3	4.6	μA	3.0V	' b11	
				0.9	12.1	33.3	μA	3.0V	' b10	
				38.0	54.0	78.0	μΑ	3.0V	`b01	
				152	190	198.5	μA	3.0V	00d'	
D201	I _{PD_WDT}	Low-Frequency Internal Oscillator/WDT	_	1.5	3.8	5.1	μA	3.0V	' b11	
D202	I _{PD_SOSC}	Secondary Oscillator (S _{OSC})	_	2.1	4.6	7.9	μA	3.0V	' b11	
D203	I _{PD_LPBOR}	Low-Power Brown-out Reset (LPBOR)		1.3	3.5	4.8	μA	3.0V	' b11	
D204	I _{PD_FVR_BUF1}	FVR Buffer 1 (ADC)	_	174.7	249.7	255.4	μA	3.0V	' b11	
D204A	I _{PD_FVR_BUF2}	FVR Buffer 2 (DAC/CMP)	_	60.0	85.0	101.0	μA	3.0V	'bx1 or 'b10	
D205	I _{PD_BOR}	Brown-out Reset (BOR)	_	16.6	20.4	20.8	μA	3.0V	' b11	
D206	I _{PD_HLVD}	High/Low Voltage Detect (HLVD)	_	16.9	20.8	22.5	μA	3.0V	' b11	
D207	I _{PD_ADCA}	ADC - Active	_	483	789	790	μA	3.0V	'bx1 or 'b10	ADC is converting (Note 4)
D208	I _{PD_CMP}	Comparator		52.5	84.2	105	μA	3.0V	' b11	

	continued									
Param.	Standard Operating Conditions (unless otherwise stated) Param. Sym. Device Min. Typ.† Max. Max. Units Conditions									
No.		Characteristics			+85°C	+125°C		V _{DD}	VREGPM	Note

^{*} These parameters are characterized but not tested.

† Data in "Typ." column is at 3.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Notes

- 1. The peripheral current is the sum of the base I_{DD} and the additional current consumed when this peripheral is enabled. The peripheral Δ current can be determined by subtracting the base I_{DD} or I_{PD} current from this limit. Max. values must be used when calculating total current consumption.
- 2. The power-down current in Sleep mode does not depend on the oscillator type. Power-down current is measured with the part in Sleep mode with all I/O pins in high-impedance state and tied to V_{SS}.
- 3. All peripheral currents listed are on a per-peripheral basis if more than one instance of a peripheral is available.
- 4. ADC clock source is ADCRC.

3. Appendix A: Revision History

Doc. Rev.	Date	Comments	
D	05/2022	Adding silicon revision D3.	
С	04/2022	Updating the flash memory cell endurance specification datasheet clarification. Adding silico erratum item 1.6.1	
В	02/2022	Adding silicon erratum items 1.1.1, 1.4.1 and 1.5.1.	
Α	01/2021	Initial document release.	

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